RD74LVC32B

Quad. 2-input OR Gates

REJ03D0224-0100Z Rev.1.00 May 11, 2004

Description

The RD74LVC32B has four 2-input OR gates in a 14 pin package. Low voltage and high speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 1.65 \text{ V to } 5.5 \text{ V}$
- All inputs V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V)
- Typical V_{OL} ground bounce < 0.8 V (@V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.0 V (@V_{CC} = 3.3 V, Ta = 25° C)
- High output current $\pm 4 \text{ mA} (@V_{CC} = 1.65 \text{ V})$

$$\pm 8 \text{ mA} (@V_{CC} = 2.3 \text{ V})$$

 $\pm 12 \text{ mA} (@V_{CC} = 2.7 \text{ V})$

$$\pm 24 \text{ mA} (@V_{CC} = 3.0 \text{ V to } 5.5 \text{ V})$$

• Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)	
RD74LVC32BFPEL	SOP–14 pin (JEITA)	FP–14DAV	FP	EL (2,000 pcs/reel)	
RD74LVC32BTELL	TSSOP-14 pin	TTP–14DV	Т	ELL (2,000 pcs/reel)	

Function Table

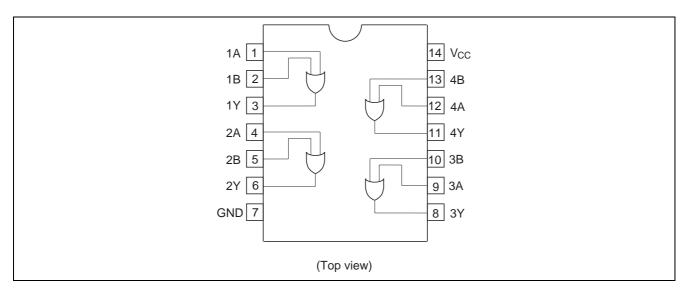
Inp			
A	Output Y		
L	L	L	
н	L	Н	
L	Н	Н	
Н	Н	Н	

H: High level

L: Low level



Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions		
Supply voltage	V _{cc}	–0.5 to 7.0	V			
Input diode current	I _{IK}	-50	mA	$V_1 = -0.5 V$		
Input voltage	VI	–0.5 to 7.0	V			
Output diode current	Ι _{ΟΚ}	-50	mA	$V_0 = -0.5 V$		
		50	mA	$V_{O} = V_{CC} + 0.5 V$		
Output voltage	Vo	–0.5 to V _{CC} +0.5	V			
Output current	Io	±50	mA			
V _{CC} , GND current / pin	I _{CC} or I _{GND}	100	mA			
Storage temperature	Tstg	–65 to +150	°C			

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.



Recommended Operating Conditions

ltem	Symbol	Ratings	Unit	Conditions		
Supply voltage	V _{cc}	1.5 to 5.5	V	Data hold		
		1.65 to 5.5		At operation		
Input / Output voltage	VI	0 to 5.5	V	A, B		
	Vo	0 to V _{CC}		Y		
Operating temperature	Та	-40 to 85	°C			
Output current	I _{OH}	-4	mA	V _{CC} = 1.65 V		
		-8		$V_{CC} = 2.3 V$		
		-12		$V_{CC} = 2.7 V$		
		-24		$V_{CC} = 3.0 \text{ V} \text{ to } 5.5 \text{ V}$		
	I _{OL}	4		V _{CC} = 1.65 V		
		8		$V_{CC} = 2.3 V$		
		12		$V_{CC} = 2.7 V$		
		24		$V_{CC} = 3.0 \text{ V} \text{ to } 5.5 \text{ V}$		
Input rise / fall time ^{*1}	t _r , t _f	20	ns/V	V_{CC} = 1.65 V to 2.7 V		
		10		$V_{CC} = 3.0 \text{ V} \text{ to } 5.5 \text{ V}$		

Notes: 1. This item guarantees maximum limit when one input switches. Waveform: Refer to test circuit of switching characteristics.



Electrical Characteristics

			Ta = -4	0 to 85°C			
ltem	Symbol	V _{cc} (V)	Min Max		Unit	Test Conditions	
Input voltage	VIH	1.65 to 1.95	V _{CC} ×0.65		V		
		2.3 to 2.7	1.7				
		2.7 to 3.6	2.0				
		4.5 to 5.5	V _{CC} ×0.7				
	V _{IL}	1.65 to 1.95	—	V _{CC} ×0.35			
		2.3 to 2.7	_	0.7			
		2.7 to 3.6	_	0.8			
		4.5 to 5.5	—	V _{CC} ×0.3			
Output voltage	V _{OH}	1.65 to 5.5	V _{CC} -0.2	_	V	I _{OH} = -100 μA	
		1.65	1.2			$I_{OH} = -4 \text{ mA}$	
		2.3	1.7	—		I _{ОН} = -8 mА	
		2.7	2.2	—		I _{OH} = -12 mA	
		3.0	2.4	—			
		3.0	2.2			I _{OH} = -24 mA	
		4.5	3.8	—			
	V _{OL}	1.65 to 5.5	—	0.2		I _{OL} = 100 μA	
		1.65	—	0.45		$I_{OL} = 4 \text{ mA}$	
		2.3	—	0.7		I _{OL} = 8 mA	
		2.7	—	0.4		I _{OL} = 12 mA	
		3.0	—	0.55		I _{OL} = 24 mA	
		4.5	—	0.55			
Input current	I _{IN}	0 to 5.5	_	±5.0	μA	$V_{IN} = 5.5 \text{ V or GND}$	
Quiescent supply current	I _{CC}	2.7 to 3.6	—	±5.0	μA	$V_{IN} = 3.6 V \text{ to } 5.5 V$	
		2.7 to 5.5		5.0		$V_{IN} = V_{CC} \text{ or } GND$	
	ΔI_{CC}	2.7 to 3.6	—	500		V_{IN} = one input at (V _{CC} -0.6)V, other inputs at V _{CC} or GND	



Switching Characteristics

			Ta = -40 to 85°C			From	То	
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	(Input)	(Output)
Propagation delay time	t _{PLH}	1.8±0.15	1.0	—	8.7	ns	A or B	Y
	t _{PHL}	2.5±0.2	1.0	—	5.4			
		2.7	1.0	—	4.4			
		3.3±0.3	1.0	—	3.8			
		5.0±0.5	1.0	_	3.5			
Between output pins skew*1	t _{OSLH}	1.8±0.15	—	—	—	ns		
	t _{OSHL}	2.5±0.2	—	—	—			
		2.7	—	_	—			
		3.3±0.3	—	—	1.0			
		5.0±0.5	—	—	1.0	1		
Input capacitance	C _{IN}	3.3	_	5.0	_	pF		

Note: 1. This parameter is characterized but not tested.

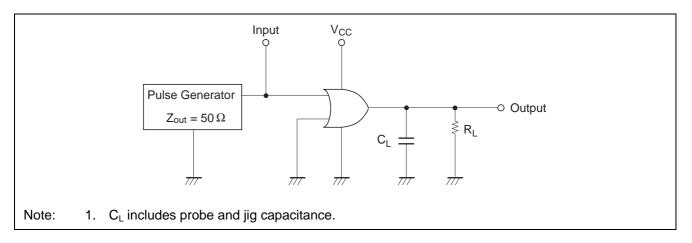
 $t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

Operating Characteristics

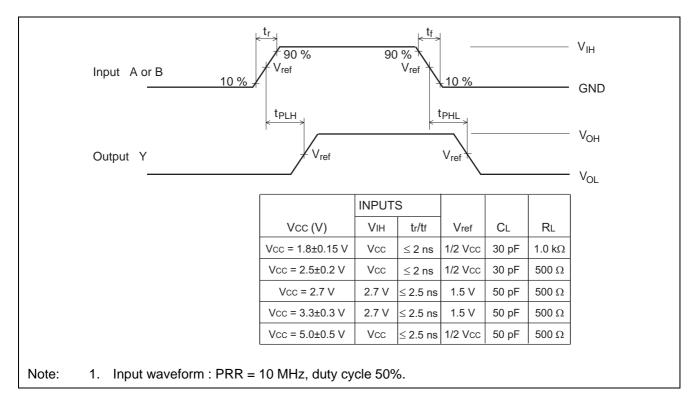
			Ta = 25°C				
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	Test conditions
Power dissipation Capacitance	C _{PD}	1.8		10	—	pF	f = 10 MHz
		2.5	_	12	—		
		3.3	_	12	—		
		5.0		15	_		



Test Circuit

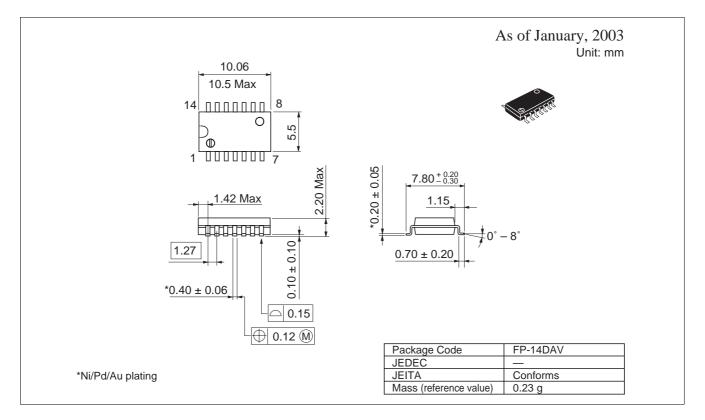


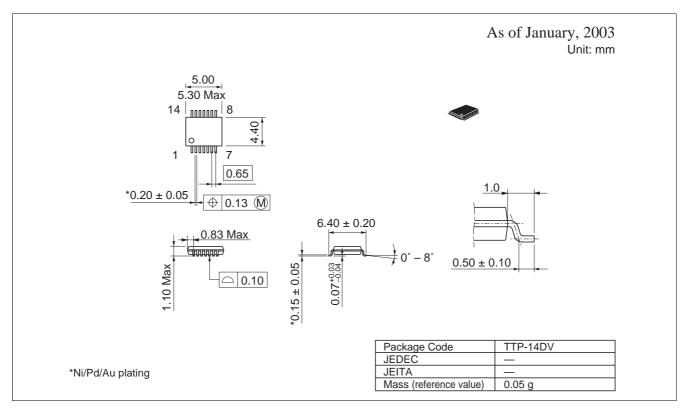
Waveforms





Package Dimensions







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